Kondo effect in complex mesoscopic structures

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(Received 20 September 2004; revised manuscript received 19 November 2004; published 21 January 2005)

We study the Kondo effect of a quantum dot placed in a complex mesoscopic structure. Assuming that electronic interactions are taking place solely on the dot, and focusing on the infinite Hubbard interaction limit, we use a decoupling scheme to obtain an explicit analytic approximate expression for the dot Green function, which satisfies certain Fermi-liquid relations at zero temperature. The details of the complex structure enter into this expression only via the self-energy for the noninteracting case. The effectiveness of the expression is demonstrated for the single-impurity Anderson model and for the T-shaped network.

DOI: 10.1103/PhysRevB.71.035333

PACS number(s): 73.21.-b, 71.27.+a

I. INTRODUCTION AND OUTLINE

The single-impurity Anderson model (SIAM) has been a paradigm of a strongly correlated electron system.¹ This seemingly simple model gives rise to dynamical screening of the local spin by the electrons in the Fermi sea, leading to a crossover from a weak coupling system at high temperatures (*T*) to a strongly coupled one at low *T*, with the relevant temperature scale given by the Kondo temperature T_K . The recent observation of the Kondo effect in quantum dots (QD's), whose parameters can be tuned continuously, and which allow probing of various properties,² has yielded strong theoretical efforts in this direction.³ Recent experiments on a QD embedded on one branch of the Aharonov-Bohm interferometer⁴ created additional interest in Kondo effects in *complex networks*.

While the high-*T* behavior of the SIAM can be adequately described by perturbation theory or poor-man scaling,⁵ and the low-T behavior is described by Fermi-liquid theory,⁶ there is no simple theory that describes the model's dynamical properties correctly in the whole temperature range, including both the high- and the low-T limits. This crossover has been described by the computationally demanding numerical renormalization group (NRG) approach.⁷ Other methods to describe the crossover are the "conserving T-matrix approximation"8 (which overestimates the unitarity sum rule), or the more limited "noncrossing approximation,"9 and to some extent, quantum Monte Carlo calculations.¹⁰ Some of these methods have also been applied to the QD in the Aharonov-Bohm interferometer.¹¹ However, none of these methods has the flexibility to follow analytically the effects of various network parameters (e.g., a magnetic flux) on experimentally measurable quantities, in particular dynamical ones.

In this paper we discuss the SIAM for a QD which is embedded in a *general complex network*. Many of the interesting physical properties of the system can be expressed explicitly in terms of the single-electron (retarded) Green function (GF) on the dot, $G_{dd\sigma}(\omega)$, for electrons with spin component σ and energy ω (measured relative to the Fermi energy). Here,

$$G_{AB\sigma}(\omega) \equiv \langle \langle A_{\sigma}; B_{\sigma}^{\dagger} \rangle \rangle \equiv -i \int_{0}^{\infty} dt \; e^{i(\omega+i\eta)t} \langle [A_{\sigma}(t), B_{\sigma}^{\dagger}]_{+} \rangle.$$
⁽¹⁾

(For the dot GF, $A=B=d_{\sigma}$, where d_{σ} destroys an electron with spin σ on the dot.) One example concerns the local density of states (LDOS) on the dot,

$$\rho_{d\sigma}(\omega) = -\operatorname{Im}[G_{dd\sigma}(\omega)]/\pi.$$
 (2)

Another example is the conductance G between two leads that are connected to sites on the network. For a general mesoscopic structure, this (linear response) conductance has the form¹²

$$\mathcal{G} = \frac{2e^2}{h} \int d\omega \left(-\frac{\partial f}{\partial \omega}\right) \widetilde{\mathcal{G}}(\omega), \qquad (3)$$

where $f(\omega)$ is the Fermi distribution function (we set the Fermi energy at $\omega=0$),

$$f(\omega) = \frac{1}{e^{\omega/kT} + 1},\tag{4}$$

and $\tilde{\mathcal{G}}(\omega)$ is often given in terms of the retarded $G_{dd\sigma}$, the advanced $G^*_{dd\sigma}$, and noninteracting parameters characterizing the network. For the simple SIAM (dot and leads), $\tilde{\mathcal{G}}(\omega)$ is proportional to $\rho_{d\sigma}(\omega)$.^{13,14}

Here we use the equations of motion method to derive a simple analytic approximate expression for $G_{dd\sigma}$, for a QD on a general network. Our approximate formula exhibits the correct behavior both at high and at very low temperatures. For simplicity, we consider a QD with a single level (of energy ϵ_d). Electron-electron interactions are assumed to exist only on the QD, and we take their energy U to be infinite. In our scheme, one first solves for the GF on the dot in the absence of the electron-electron interactions, i.e., U=0. This (spin-independent) GF can be written in the form

$$G_{dd}^{0}(\omega) = \frac{1}{\omega + i\eta - \epsilon_d - \Sigma_0(\omega)},$$
(5)

with the energy-dependent (complex) self-energy (SE)

$$\Sigma_0(\omega) \equiv \delta \epsilon_d(\omega) - i\Delta(\omega). \tag{6}$$

This is easily done exactly, for any finite network; it only involves the solution of a finite set of linear equations. Our approximate explicit expression for $G_{dd\sigma}(\omega)$ is then given in a single equation [see Eq. (53) below]. Somewhat surprisingly, this equation depends on the network parameters only via $\Sigma_0(\omega)$. Although approximate, this expression allows for detailed systematic investigations of the Kondo effect as function of the system parameters, on a variety of complex networks. Even if sometimes only qualitatively correct, such systematic studies help to investigate new physical phenomena on a broad variety of mesoscopic systems. Furthermore, the dynamical mean field theory¹⁵ (which was developed to address the physics of the periodic Anderson and Hubbard models) iterates the local GF of the SIAM, which is calculated at each stage in terms of the effective SE created by the rest of the lattice. Since our GF is easily calculated in terms of Σ_0 , it is an ideal candidate for such calculations. We are not aware of alternative simple analytic expressions that obey the necessary requirements at both high and low T.

In Sec. II we follow Refs. 16-19, and derive the equation of motion (EOM) for the dot GF. Extending these references, this EOM is derived here for a generalized case, in which the dot "sits" within an arbitrary complex network. The EOM for the dot GF involves higher-order GF's (consisting of more operators), whose EOM's introduce in turn more GF's. One then terminates this hierarchy by decoupling out averages of operators. The latter are then found using the fluctuationdissipation relationship, from the relevant GF's. In this manner, the treatment becomes self-consistent. The successful decoupling must keep as much of the electronic correlation as possible.¹⁷ For example, a widely used earlier approximation¹⁴ neglected some dot-lead correlations and therefore gave reasonable results only at $T > T_K$. For this reason, Gerland et al.²⁰ had to combine the EOM method at high T with the NRG at low T. After we correct these earlier calculations, and include all the necessary correlations, we obtain good results for all T. An earlier application of the EOM method solved the integral equations numerically, on the simplest interferometer geometry.²¹

The above decoupling scheme produces an integral equation for $G_{dd\sigma}(\omega)$, which generalizes that found in Refs. 18 and 22. An approximate analytical solution for this equation is found in Sec. III. The low-temperature limit, the Fermiliquid conditions, and the Kondo behavior are discussed in Sec. IV. Unlike earlier papers (spanning over four decades), our solution gives good qualitative results for the *whole parameter range*: It has the correct high-*T* behavior and satisfies several low-*T* Fermi-liquid relations.

For the simplest SIAM, the "network" is represented by a band with a density of states $N(\omega)$. In the broadband limit, the self-energy on the QD can be approximated by its value at the Fermi energy, $\Sigma_0(\omega) \approx -i\Delta_b = -i\pi V^2 N(0)$, and Δ_b represents the width of the impurity state in the absence of interactions (V represents the approximately energyindependent dot-band coupling). In this case, our equations reduce to those discussed in the earlier literature. We emphasize again that even the solution for this simple case is nontrivial, since earlier work either did not have a close analytical formula or missed some correlations, leading to wrong results at low T.

As stated, our result for $G_{dd\sigma}(\omega)$ depends on the details of the general network only via the noninteracting self-energy $\Sigma_0(\omega)$. To demonstrate the power of our result, we present here a few simple examples. Section V contains explicit results for the simple case of the SIAM, when the QD is coupled to two one-dimensional leads. For this case, we easily calculate various features of the Kondo behavior, including the peak in $\rho_{dd\sigma}$ at the Fermi energy, the plateau in the conductance in the so-called unitary limit, and the plateau in the "transmission phase" at $\pi/2$.

A second example, of the so-called "T" network, is solved in Sec. VI. In this case, one has interference between the wave function on the dot and that on the intersection point. Our simple approximate formula exhibits the Fano vanishing of the transmission and the associated so-called anti-Kondo effect, as seen experimentally.²³ Here we also extend earlier theoretical work, which used complicated techniques.^{24,25} Finally, Sec. VII contains our summary.

II. EQUATIONS OF MOTION

A. The Hamiltonian

Our Hamiltonian

$$\mathcal{H} = \mathcal{H}_{dot} + \mathcal{H}_{net} + \mathcal{H}_{dot-net}, \tag{7}$$

contains the dot part

$$\mathcal{H}_{d} = \epsilon_{d} \sum_{\sigma} n_{d\sigma} + U n_{d\uparrow} n_{d\downarrow}, \qquad (8)$$

with a single energy level ϵ_d and an electron-electron interaction $U(n_{d\sigma} = d^{\dagger}_{\sigma} d_{\sigma})$. All the other parts of \mathcal{H} can be arbitrary, but noninteracting:

$$\mathcal{H}_{\text{net}} = \sum_{n\sigma} \epsilon_n a_{n\sigma}^{\dagger} a_{n\sigma} - \sum_{nm\sigma} J_{nm} a_{n\sigma}^{\dagger} a_{m\sigma} \tag{9}$$

describes the network without the dot, and

$$\mathcal{H}_{\text{dot-net}} = -\sum_{n\sigma} \left(J_{dn} d_{\sigma}^{\dagger} a_{n\sigma} + \text{H.c.} \right)$$
(10)

describes the coupling of the dot to the network. Here, $a_{n\sigma}^{\dagger}$ creates an electron with spin σ and energy ϵ_n on the site *n* of the network. The coefficients J_{nm} and J_{dn} represent tightbinding hopping matrix elements. In the absence of a magnetic flux, these coefficients can be chosen to be real. The flux then turns them complex, with phases that relate to the Aharonov-Bohm effect and with $J_{nm} = J_{mn}^{*}$.^{11,21,26}

The main part of this paper concerns the above general Hamiltonian, which assumes no specific details on the structure of the network. However, for some specific applications, it is convenient to attach a finite mesoscopic network to several semi-infinite leads, which connect to electron reservoirs. We thus divide \mathcal{H}_{net} into two parts,

$$\mathcal{H}_{\text{net}} = \mathcal{H}_{\text{meso}} + \mathcal{H}_{\text{leads}},\tag{11}$$

where \mathcal{H}_{meso} has the same form as \mathcal{H}_{net} , except that the sum is restricted to sites that belong to the finite mesoscopic part of the net (excluding the dot and the leads), and

$$\mathcal{H}_{\text{leads}} = \sum_{L} \left(\mathcal{H}_{L} - \sum_{n_{L},r} \left(J_{n_{L},r} a_{n_{L}\sigma}^{\dagger} c_{r\sigma}^{(L)} + \text{H.c.} \right) \right),$$

$$\mathcal{H}_{L} = -\sum_{rs} J_{rs} c_{r\sigma}^{(L)\dagger} c_{s\sigma}^{(L)} + \text{H.c.}$$
(12)

Here n_L are the indices of the points on the mesoscopic structure that are connected to lead number *L*, while $c_{r\sigma}^{(L)}$ destroys an electron of spin σ on the site *r* of the lead.

Usually, the lead *L* has a continuous spectrum, with eigenstates $|k\rangle$ and eigenenergies ϵ_k , in a band of width 2*D*. Equation (12) can then be written as

$$\mathcal{H}_{\text{leads}} = \sum_{L} \left(\mathcal{H}_{L} - \sum_{n_{L},k} \left(V_{n_{L}}(k) a^{\dagger}_{n_{L}\sigma} c^{(L)}_{k\sigma} + \text{H.c.} \right) \right),$$

$$\mathcal{H}_{L} = \sum_{k} \epsilon_{k} c^{(L)\dagger}_{k\sigma} c^{(L)}_{k\sigma},$$
(13)

and also

$$\mathcal{H}_{\text{dot-net}} = -\sum_{n\sigma} J_{dn} d_{\sigma}^{\dagger} a_{n\sigma} - \sum_{L} \sum_{k\sigma} V_{d}(k) d_{\sigma}^{\dagger} c_{k\sigma}^{(L)} + \text{H.c.},$$
(14)

with obvious definitions. When the network consists only of the dot and the leads (i.e., $\mathcal{H}_{meso}=0$) then this has exactly the form of the standard SIAM model, discussed broadly in the literature. If all the leads have similar bands, then the electrons in the whole system also have a continuous spectrum in the range $-D < \omega < D$. All integrals over ω below will be thus over this energy band, and it is due to resonances in such integrals that we need to calculate the retarded GF at $\omega+i\eta$.

B. Derivation of $\Sigma_0(\omega)$

From now on we return to the general Hamiltonian Eqs. (7)–(10). The EOM for the retarded GF on the QD reads

$$(\omega + i\eta - \epsilon_d)G_{dd\sigma} = 1 - \sum_n J_{dn}G_{nd\sigma} + U\Gamma_\sigma, \qquad (15)$$

where

$$\Gamma_{\sigma} = \langle \langle n_{d-\sigma} d_{\sigma}; d_{\sigma}^{\dagger} \rangle \rangle. \tag{16}$$

From now on, we shall use the shorthand ω for $\omega + i\eta$, except where it matters. Specifically,

$$(\omega - \epsilon_n)G_{nd\sigma} = -J_{dn}^*G_{dd\sigma} - \sum_m J_{nm}G_{md\sigma}.$$
 (17)

We next define the matrix

$$\mathcal{M}(\omega)_{nm} \equiv \langle n | \omega - \mathcal{H}_{\text{net}} | m \rangle \equiv J_{nm} + \delta_{nm}(\omega - \epsilon_n), \quad (18)$$

which represents the system without the dot. In the following, we shall need the inverse matrix

$$\mathcal{F}(\omega) \equiv [\mathcal{M}(\omega)]^{-1}, \qquad (19)$$

which is the Green function for the system without the dot. With this definition one finds

$$G_{md\sigma} = u_m(\omega)G_{dd\sigma},\tag{20}$$

where

$$u_m(\omega) \equiv -\sum_n \mathcal{F}(\omega)_{mn} J_{nd}.$$
 (21)

We can now calculate the second term on the right-hand side (RHS) of Eq. (15), and show that

$$-\sum_{n} J_{dn} G_{nd\sigma} = \Sigma_0 G_{dd\sigma}, \qquad (22)$$

with

$$\Sigma_0(\omega) \equiv -\sum_m J_{dm} u_m(\omega) \equiv \sum_{mn} J_{dm} \mathcal{F}(\omega)_{mn} J_{nd}.$$
 (23)

At U=0, Eq. (15) thus reduces to Eq. (5). Clearly, Σ_0 can be calculated for the noninteracting case.

All the other GF's can similarly be expressed in terms of $G_{dd\sigma}$. For example,

$$G_{dm\sigma} = u_m^*(\omega^*)G_{dd\sigma}, \qquad (24)$$

where $\omega^* \equiv \omega - i\eta$. Another way to represent $u_m^*(\omega^*)$ is to start from $u_m(\omega)$, and then take the complex conjugate only of the hopping coefficients J_{mn} (namely, reverse all their phases), without touching $\omega + i\eta$. Similarly,

$$G_{\ell m\sigma} = \mathcal{F}(\omega)_{\ell m} + u_{\ell}(\omega)G_{dm\sigma}.$$
(25)

Since \mathcal{M} is an infinite matrix, its inversion may not be trivial. Formally, we can denote the eigenenergies and eigenstates of \mathcal{H}_{net} by ϵ_a and $|a\rangle$, and then write

$$\mathcal{F}(\omega)_{mn} = \sum_{a} \langle m | a \rangle \frac{1}{\omega + i \eta - \epsilon_a} \langle a | n \rangle.$$
⁽²⁶⁾

However, in the examples it is useful first to eliminate the parts that involve the sites on the leads. Examples for this procedure are presented in Appendix A.

C. EOM's for higher-order GF's

The EOM for Γ_{σ} (with only on-site Hubbard interaction on the dot) does not involve GF's of more arguments:

$$(\boldsymbol{\omega} - \boldsymbol{\epsilon}_d - \boldsymbol{U})\Gamma_{\sigma} = \langle \boldsymbol{n}_{d-\sigma} \rangle + \sum_n J_{dn}^* \Gamma_{n\sigma}^{(3)} - \sum_n J_{dn} (\Gamma_{n\sigma}^{(1)} + \Gamma_{n\sigma}^{(2)}),$$
(27)

with three new GF's,

$$\Gamma_{n\sigma}^{(1)} = \langle \langle n_{d-\sigma} a_{n\sigma}; d_{\sigma}^{\dagger} \rangle \rangle$$

(28)

$$\Gamma_{n\sigma}^{(3)} = \langle \langle a_{n-\sigma}^{\dagger} d_{-\sigma} d_{\sigma}; d_{\sigma}^{\dagger} \rangle \rangle$$

 $\Gamma_{n\sigma}^{(2)} = \langle \langle d_{-\sigma}^{\dagger} a_{n-\sigma} d_{\sigma}; d_{\sigma}^{\dagger} \rangle \rangle,$

The inhomogeneous term in Eq. (27), $\langle n_{d-\sigma} \rangle$, represents the average number of electrons with spin σ on the dot. This number needs to be determined self-consistently, via the fluctuation-dissipation theorem:

$$\langle n_{d\sigma} \rangle = \int d\omega f(\omega) \rho_{d\sigma}(\omega).$$
 (29)

We shall return to this condition below.

We now write the EOM's for the new GF's, $\Gamma_{n\sigma}^{(i)}$, and use several approximations for their solution. First, it is easy to see from the EOM for $\Gamma_{n\sigma}^{(3)}$ that this GF is of order 1/U. Therefore, it contributes to Γ_{σ} only at order $1/U^2$, and can be ignored for $U \rightarrow \infty$ [we need Γ_{σ} only to order 1/U; see Eq. (15)]. Second, we introduce a decoupling scheme for the new GF's that appear in the EOM's of the $\Gamma_{n\sigma}^{(i)}$'s,

$$\langle \langle a_{n\sigma_1}^{\dagger} a_{m\sigma_2} d_{\sigma_3}; d_{\sigma}^{\dagger} \rangle \rangle \simeq \langle a_{n\sigma_1}^{\dagger} a_{m\sigma_1} \rangle \delta_{\sigma_1 \sigma_2} \langle \langle d_{\sigma_3}; d_{\sigma}^{\dagger} \rangle \rangle - \langle a_{n\sigma_1}^{\dagger} d_{\sigma_1} \rangle \delta_{\sigma_1 \sigma_3} \langle \langle a_{m\sigma_2}; d_{\sigma}^{\dagger} \rangle \rangle.$$
(30)

We omit thermal averages of the form $\langle a_{n\sigma}d_{\sigma}\rangle$, which include two destruction (or creation) operators, and $\langle a_{n\sigma}^{\dagger}a_{m\sigma'}\rangle$ with $\sigma \neq \sigma'$, relevant only for states with a net magnetic moment. The latter assumption means that we restrict the discussion only to symmetric states, with $G_{dd\uparrow}=G_{dd\downarrow}$.

Using these approximations, the EOM for $\Gamma_{n\sigma}^{(1)}$ becomes

$$(\omega - \epsilon_n)\Gamma_{n\sigma}^{(1)} = -J_{dn}^*\Gamma_{\sigma} - \sum_m J_{nm}\Gamma_{m\sigma}^{(1)}.$$
 (31)

The derivation of this equation also required an additional term, $-G_{nd\sigma}[\Sigma_m J_{dm} \langle d^{\dagger}_{-\sigma} a_{m-\sigma} \rangle - \text{c.c.}]$. However, this term vanishes. Here and below, we calculate equilibrium thermal averages by using the fluctuation-dissipation theorem,

$$\langle A^{\dagger}B\rangle = \int \left(-\frac{d\omega}{2\pi i}\right) f(\omega) (G_{BA} - G_{AB}^*).$$
(32)

Equation (31) is practically the same as Eq. (17), which was used to derive Σ_0 in terms of the J_{nm} 's. Applying the same algebra to Eq. (31) then yields the analog to Eq. (22),

$$-\sum_{n} J_{dn} \Gamma_{n\sigma}^{(1)} = \Sigma_0 \Gamma_{\sigma}.$$
(33)

Using the same approximations, the EOM of $\Gamma_{n\sigma}^{(2)}$ is

$$(\omega - \epsilon_n)\Gamma_{n\sigma}^{(2)} = -J_{dn}^*\Gamma_{\sigma} - \sum_m J_{nm}\Gamma_{m\sigma}^{(2)} + \langle X_n \rangle G_{dd\sigma} + \langle d_{-\sigma}^{\dagger} a_{n-\sigma} \rangle (1 + \Sigma_0 G_{dd\sigma}), \qquad (34)$$

in which

$$\langle X_n \rangle = \sum_m J_{dm}^* \langle a_{m-\sigma}^{\dagger} a_{n-\sigma} \rangle.$$
(35)

Although the first two terms on the RHS of Eq. (34) are similar to those in Eq. (31), we now need to calculate the

other two terms. Since these terms require thermal averages, which we express using the fluctuation-dissipation Eq. (32), they end up with integrals that involve $G_{dd-\sigma}$ leading finally to our integral equation for the dot GF. The details of these calculations are presented in Appendix B.

Inserting the results for the necessary thermal averages into the RHS of Eq. (34), the results are used in Eq. (B5) for the combination $-\sum_n J_{dn} \Gamma_{n\sigma}^{(2)}$ which is needed in the RHS of Eq. (27). Adding also the corresponding combination for $\Gamma^{(1)}$ [Eq. (33)] yields our final result for Γ_{σ} . It remains to insert it back into the EOM (15) for the dot Green function $G_{dd\sigma}$. This yields an integral equation for this function,

$$(\omega - \epsilon_d - \Sigma_0)G_{dd\sigma} = 1 - \langle n_{d-\sigma} \rangle + G_{dd\sigma} \int \left(-\frac{d\omega'}{2\pi i} \right)$$

$$\times \frac{f(\omega')}{\omega - \omega' + i\eta} [(1 + \Sigma_0'G'_{dd-\sigma})(\Sigma_0' - \Sigma_0) - (\omega' \to \omega'^*)] + (1 + \Sigma_0 G_{dd\sigma}) \int \left(-\frac{d\omega'}{2\pi i} \right) \frac{f(\omega')}{\omega - \omega' + i\eta}$$

$$\times [G'_{dd-\sigma}(\Sigma_0 - \Sigma_0') - (\omega' \to \omega'^*)],$$

$$\eta \to 0^+. \tag{36}$$

Here and below, $G_{dd\sigma}$ and Σ_0 are understood to be functions of $\omega \rightarrow \omega + i\eta$, and the primes denote a dependence on $\omega' \rightarrow \omega' + i\eta$, with ${\omega'}^* \rightarrow \omega' - i\eta$. Two comments are in place here. First, for the simplest SIAM, when $\Sigma_0(\omega) \approx -i\Delta_b$ is independent of ω , we have $\Sigma_0(\omega^*) \approx i\Delta_b$, so that only the parts with ${\omega'}^*$ survive. Furthermore, in this case one can factorize Δ_b out of the integrals. This reproduces the integral equation of Lacroix,¹⁸

$$(\omega - \epsilon_{d} + i\Delta_{b})G_{dd\sigma} = 1 - \langle n_{d-\sigma} \rangle - 2i\Delta_{b} \left[G_{dd\sigma} \int \left(-\frac{d\omega'}{2\pi i} \right) \right] \\ \times \frac{f(\omega')}{\omega - \omega' + i\eta} (1 + i\Delta_{b}[G'_{dd-\sigma}] *) \\ - (1 - i\Delta_{b}G_{dd\sigma}) \\ \times \int \left(-\frac{d\omega'}{2\pi i} \right) \frac{f(\omega')}{\omega - \omega' + i\eta} [G'_{dd-\sigma}] * .$$

$$(37)$$

However, even for this simple case there has not been an analytic solution that covers the whole parameter range. Second, discarding¹⁴ correlations between the dot and other sites on the net, e.g., $\langle d^{\dagger}_{\sigma}a_{n\sigma}\rangle$, amounts to neglecting the terms containing G'_{dd} in Eq. (36). This ends up with a breakdown of the Fermi-liquid conditions at T=0, and with a bad approximation for $T < T_K$.

III. APPROXIMATE SOLUTION OF THE INTEGRAL EQUATION

We now restrict the discussion to "nonmagnetic" states, and replace $G_{dd\uparrow} = G_{dd\downarrow} \equiv G_{dd}$. Equation (36) can then be written as

$$(\omega - \epsilon_d - \Sigma_0)G_{dd} = \delta n + \mathcal{A}G_{dd} - \mathcal{B}(1 - i\Delta G_{dd}), \quad (38)$$

where $\delta n = 1 - \langle n_{d\uparrow} \rangle = 1 - \langle n_{d\downarrow} \rangle \equiv 1 - \langle n_{d\downarrow} \rangle / 2$ and \mathcal{A} and \mathcal{B} are functions of ω , given by

$$\mathcal{A}(\omega) = \int \left(-\frac{d\omega'}{2\pi i}\right) \frac{f(\omega')}{\omega - \omega' + i\eta} \times \left[\Sigma_0'(1 + G_{dd}'(\Sigma_0' - \Sigma_0)) - (\omega' + i\eta \to \omega' - i\eta)\right],$$
$$\mathcal{B}(\omega) = \int \left(-\frac{d\omega'}{2\pi i}\right) \frac{f(\omega')}{\omega - \omega' + i\eta} \times \left[G_{dd}'(\Sigma_0' - \Sigma_0) - (\omega' + i\eta \to \omega' - i\eta)\right].$$
(39)

For reasons that will be explained later, it is now convenient to replace $f(\omega')$ inside the integrals by $[f(\omega')-1/2] + 1/2$. The part related to the constant 1/2 can then be calculated using the Kramers-Kronig relations,

$$\int \left(-\frac{d\omega'}{2\pi i}\right) \frac{1}{\omega - \omega' + i\eta} [F(\omega') - F(\omega')^*] \equiv F(\omega),$$
(40)

and thus we find

$$\mathcal{A}(\omega) = \frac{1}{2} \Sigma_0(\omega) + \int \left(-\frac{d\omega'}{2\pi i} \right) \frac{f(\omega') - 1/2}{\omega - \omega' + i\eta} \\ \times \left[\Sigma_0'(1 + G_{dd}'(\Sigma_0' - \Sigma_0)) - (\omega' + i\eta \to \omega' - i\eta) \right],$$

$$\mathcal{B}(\omega) = \int \left(-\frac{d\omega'}{2\pi i} \right) \frac{f(\omega') - 1/2}{\omega - \omega' + i\eta} \times \left[G'_{dd}(\Sigma'_0 - \Sigma_0) - (\omega' + i\eta \to \omega' - i\eta) \right].$$
(41)

We next follow Lacroix,¹⁸ and assume that the integrals are dominated by the region $\omega' \simeq \omega$, namely, that

$$\int d\omega' F(\omega,\omega') \frac{f(\omega') - 1/2}{\omega - \omega' + i\eta} \simeq F(\omega,\omega) X(\omega), \qquad (42)$$

and thus

$$\mathcal{B}(\omega) \approx \Delta(\omega) G_{dd}^*(\omega) X(\omega), \qquad (43)$$

where $\Delta(\omega) = -\text{Im}\Sigma_0(\omega)$ and 22

$$X(\omega) = \int_{-D}^{D} \frac{d\omega'}{\pi} \frac{f(\omega') - 1/2}{\omega - \omega' + i\eta} = \frac{1}{\pi} \left[\frac{1}{2} \ln \frac{\beta^2 (D^2 - \omega^2)}{(2\pi)^2} - \Psi \left(\frac{1}{2} + \frac{\beta \omega}{2\pi i} \right) \right]$$
(44)

(Ψ is the Digamma function). A similar procedure yields

$$\mathcal{A}(\omega) \approx \Delta(\omega) \left(-\frac{i}{2} + X(\omega) [1 + i\Delta(\omega) G_{dd}^*(\omega)] \right).$$
(45)

The reason for using the above transformation is that when one analyzes the equivalent equations for finite U, then one requires particle-hole symmetry, namely, the relation

$$\widetilde{G}_{dd}(\omega) = -G_{dd}^*(-\omega), \qquad (46)$$

where the tilde denotes particle-hole transformed quantities. In that case, this relation is equivalent to the relations

$$\mathcal{B}(\omega) = -\mathcal{B}^*(-\omega),$$

$$\widetilde{\mathcal{A}}(\omega) = \mathcal{A}^*(-\omega) - \Sigma_0^*(-\omega).$$
(47)

These relations should hold also for any approximate solution.¹⁶ It is easy to check that these relations are obeyed by our approximate expressions (43) and (45), but would not hold if we made the approximation (42) on the original equations, before shifting $f(\omega')$ by 1/2.^{16,18}

Taking δn as a parameter, and defining the scaled variable

$$z(\omega) \equiv \frac{\omega - \epsilon_d - \delta \epsilon_d(\omega)}{2\Delta(\omega)},\tag{48}$$

the solution of Eq. (38) can be written as

$$G_{dd}(\omega) = g(\omega) [\delta n + iQ(\omega)/X * (\omega)], \qquad (49)$$

with

$$g = \frac{1}{\omega - \epsilon_d - \delta \epsilon_d + i3\Delta/2} \equiv \frac{1}{2\Delta(z + 3i/4)},$$
 (50)

$$Q = S - \left[S^2 + |X|^2 \left(\frac{3}{2} \,\delta n - \delta n^2 \right) \right]^{1/2},\tag{51}$$

$$S = z^2 + \frac{9}{16} - z \operatorname{Re} X + \left(\delta n - \frac{3}{4}\right) \operatorname{Im} X,$$
 (52)

and we have omitted the explicit dependence on ω for brevity. For some purposes it is more convenient to write Eq. (49) as

$$G_{dd}(\omega) = \frac{\frac{3}{2}}{1 - \mathcal{C}(\omega)} \frac{1}{\omega - [\epsilon_d + \delta E_d(\omega)] + i\frac{3}{2}\Delta(\omega)},$$
 (53)

where the real functions $C(\omega)$ and $\delta E_d(\omega)$, which result from the strong interactions on the dot, depend on *T* and on $\Sigma_0(\omega)$ and are given by

$$\delta E_d(\omega) = \delta \epsilon_d - 2\Delta (\operatorname{Re} X)\mathcal{C}/(1-\mathcal{C}),$$

$$\mathcal{C}(\omega) = \frac{1}{2\Delta^2 Q |g(i+\delta nX^*/Q)|^2} \equiv \frac{2(z^2+9/16)}{Q |i+\delta nX^*/Q|^2}.$$
(54)

Equation (53) forms our general result. We emphasize again that all we need to know is the noninteracting self-energy $\Sigma_0(\omega)$.

As seen explicitly from the above equations, our analytic expression for G_{dd} depends on the parameter $\delta n = 1 - \langle n_d \rangle / 2$, which needs to be determined self-consistently, via Eq. (29). We discuss this condition in a specific example below.

IV. THE FERMI-LIQUID RELATIONS AND THE KONDO TEMPERATURE

At T=0, one easily sees that

$$\operatorname{Re} X(\omega) \approx \ln |D/\omega|/\pi,$$
 (55)

diverging at the Fermi energy $\omega \rightarrow 0$. At $T=\omega=0$ we thus have $\mathcal{C}\rightarrow 0$ and $\mathcal{C} \operatorname{Re} X \rightarrow u(z)$, with

$$u(z) = \frac{2(z^2 + 9/16)[z + \sqrt{z^2 + \delta n(1.5 - \delta n)}]}{[z + \sqrt{z^2 + \delta n(1.5 - \delta n)}]^2 + \delta n^2},$$
 (56)

and $z=z(\omega=0)=-[\epsilon_d+\delta\epsilon_d(0)]/[2\Delta(0)]$. Therefore,

$$G_{dd}(0) = \frac{1}{\Delta(0)\{(4/3)[z - u(z)] + i\}}.$$
(57)

For a very deep level on the dot, $z \ge 1$, u(z) approaches z, and G_{dd} approaches $-i/\Delta(0)$, ending up with high plateaus in the LDOS and in the phase of the complex $G_{dd}(\omega)$ sticking to $\pi/2$. All of these characteristics, which are hallmarks of the Kondo behavior,²⁰ are observed in the examples below. As ϵ_d moves up from large negative values, Eq. (57) shows a gradual crossover away from this "unitary" limit, and G_{dd} approaches the non-interacting G_{dd}^0 as $z \to -\infty$.

Equation (57) also ensures that the GF obeys the Fermiliquid relations²⁷ at T=0: (i) The imaginary part of the SE on the Fermi level is the same as in the absence of interactions, i.e., $-\Delta(0)$, confirming the unitarity limit;^{28,13} (ii) For $\epsilon_d \ll$ $-\Delta$, the LDOS there [i.e., $\rho_d(\omega=0) \equiv \rho_{d\sigma}(0)$] approaches the finite value $1/[\pi\Delta(0)]$. We emphasize that these results apply for *any* complex network; the only input is $\Sigma_0(\omega)$.

The Kondo effect concerns the behavior of the density of states near the Fermi energy at low temperature. In that regime, G_{dd} is dominated by its imaginary part, and thus

$$\rho_d \approx 1/[\pi\Delta(\omega)(1-\mathcal{C})]. \tag{58}$$

For Re $X(\omega) > z(\omega) \ge 1$, one has $S \approx z(z - \text{Re } X) < 0$, $Q \approx 2S$, and the leading ω dependence of C is

$$C \sim \frac{z}{z - \operatorname{Re} X}.$$
(59)

We thus end up with a logarithmic cusp in ρ_d at $\omega=0$. The related narrow peak reaches one-half of its peak value (equal to $1/[\pi\Delta(0)])$ when $\mathcal{C}\approx-1$. One definition of the Kondo energy T_K is to identify T_K with the half-width of this peak. Solving $\mathcal{C}(\omega=\pm T_K)=-1$ and using Eq. (59) thus yields Re X=2z, i.e.,

$$T_{K}(\boldsymbol{\epsilon}_{d}) = D \exp[-a\pi|\boldsymbol{\epsilon}_{d} + \delta\boldsymbol{\epsilon}_{d}(0)|/\Delta(0)], \qquad (60)$$

with a=1. This result, which agrees with that of Lacroix,¹⁸ is qualitatively similar but quantitatively different from the presumably exact T_K as given by Haldane,²⁹ which has a=1/2. However, T_K only represents some crossover energy scale, and we expect the above solution to follow the qualitative variations of T_K with the system parameters, which are contained in $\delta \epsilon_d$ and in Δ . It should be emphasized that T_K depends on both Δ and $\delta \epsilon_d$ (some authors ignore the part coming from the real part of the SE, $\delta \epsilon_d$). For example, for the Aharonov-Bohm interferometer T_K oscillates with the flux.³⁰

At the Fermi energy, $\omega = 0$, and for fixed $\epsilon_d < 0$, one expects $\rho_d(0)$ to decrease with increasing *T*. In this limit, $X(\omega=0)=\ln|AD/T|/\pi$, with $A=e^{-\Psi(1/2)}/(2\pi)\approx 1.133$ 87. For $|\epsilon_d| \ge \Delta(0)$ we then find the asymptotic relation

$$\rho_d(0) \approx \frac{1}{\pi \Delta(0)(1-C)} \sim \frac{\operatorname{Re} X - z}{\pi \Delta(0) \operatorname{Re} X}$$
$$= \frac{1}{\pi \Delta(0)} \left(1 + \frac{\pi(\epsilon_d + \delta \epsilon_d)}{2\Delta(0) \ln(AD/T)} \right).$$
(61)

This density of states decreases to one-half of its maximum T=0 value at a temperature AT_K , with T_K given in Eq. (60). Although the result (61) is qualitatively correct, and is also consistent with our T_K , its explicit low-temperature dependence disagrees with exact expectations: we obtain a logarithmic behavior, whereas Fermi-liquid theory predicts a T^2 dependence at low $T.^{6,7}$ This is an artifact of our approximation. However, at high T we do recover the usual logarithmic variation.

In the opposite limit, of $|z| \ge \operatorname{Re} X \sim 1$, one finds that $|Q/X| \le 1$, and Eq. (49) implies that $G_{dd}(\omega)$ approaches $\delta n g(\omega)$. The appearance of δn in the numerator, in place of 1, results from the fact that some weight of the spectral function is pushed to infinite U.¹⁴ Another interesting point concerns the factor 3/2 in Eqs. (50) and (53). This factor may be explained heuristically³¹ by the fact that while both spin directions are accessible for tunneling into the dot, only a single one can tunnel out of it.

V. EXAMPLE 1: THE SIMPLE SIAM

In the following two examples, we assume simple semiinfinite one-dimensional leads, with identical nearestneighbor hopping matrix elements -J, and with a lattice constant *a*. The eigenenergies of each \mathcal{H}_L are therefore $\epsilon_k =$ $-2J \cos ka$, with eigenfunctions $\langle n | k \rangle = \sin nka \sqrt{2/\Omega}$ ($\Omega \rightarrow \infty$ is the length of the lead), and D=2J. We also assume that the leads *L* and *R* are attached to the mesoscopic network only at one site, with hopping matrix elements J_ℓ and J_r . For the simple SIAM, when the two leads are directly connected to the dot, we show in Appendix A that the leads generate a self-energy

$$\Sigma_0(\omega) = -e^{i|q|a} (|J_\ell|^2 + |J_r|^2) / J \equiv -e^{i|q|a} \Delta_b$$
(62)

on the dot, with q determined by $\omega = -2J \cos qa$ and with

$$\Delta_b \equiv \Gamma_\ell + \Gamma_r. \tag{63}$$

Here we have used the notation

$$\Gamma_{\ell,r} \equiv |J_{\ell,r}|^2 / J = \pi \mathcal{N}(0) |J_{\ell,r}|^2, \tag{64}$$

with $\mathcal{N}(\omega)$ being the density of the band states. The width of the noninteracting resonance at ϵ_d is thus equal to $\Delta_b \sin qa$. In the figures presented below we use the symmetric case, $\Gamma_\ell = \Gamma_r = \Delta_b/2$. Substituting $\Sigma_0(\omega) = \delta \epsilon_d(\omega) - i\Delta(\omega)$ into Eqs. (49)–(52) then yields G_{dd} .



FIG. 1. The self-consistent average occupation on the dot, $\langle n_d \rangle$ (thick line), and the Friedel added occupation \tilde{n} at T=0, as function of ϵ_d , for the simplest SIAM with $\Delta_b/J=0.1$. Results remain almost unchanged up to $T \sim \Delta_b$.

We start by discussing the self-consistency condition for $\langle n_d \rangle$. Figure 1 shows an example of our self-consistent solutions for $\langle n_d \rangle$, at T=0: we start from an initial guess for δn , then calculate $\langle n_d \rangle$ from Eq. (29), and iterate; the procedure converges after a few iterations. Also shown is \tilde{n} , which represents the total change in the electron occupation in the system due to the dot, as determined from the Friedel phase, defined via^{13,28,27}

$$\tan\left(\frac{\pi}{2}(1-\tilde{n})\right) \equiv \operatorname{Re}[G_{dd}(0)]/\operatorname{Im}[G_{dd}(0)].$$
(65)

For $\epsilon_d \ll -\Delta(0) = -\Delta_b$, \tilde{n} approaches 1, while $\langle n_d \rangle$ remains slightly smaller. This small difference could reflect an additional occupation of other sites in the leads. It could also result from the inaccuracy of our approximation for $G_{dd}(\omega)$, which becomes worse as ω moves away from the Fermi energy; the integral in Eq. (29) contains contributions from all ω . However, this small difference has only a small effect on the other calculations presented below.

Although it is easy to solve for $\langle n_d \rangle$ for each set of parameters and use the resulting δn for other calculations, the qualitative results are only weakly affected if one uses an arbitrary smooth variation of $\langle n_d \rangle$ from 0 to 1 as ϵ_d varies from $+\infty$ to $-\infty$. In the calculations below, we used such a smooth variation for δn , with a width of order Δ_b .

An alternative approximate expression for δn follows from Eq. (49). It turns out that for most of the integration range in Eq. (29), $G_{dd}(\omega)$ is dominated by the first term there. Neglecting the second term, one has $1 - \delta n = \langle n_{d\sigma} \rangle \approx \delta n n_0$, with $n_0 = -\int d\omega \operatorname{Im}[g(\omega)]/\pi$ depending only on the noninteracting parameters. Thus, $\delta n \approx 1/(1+n_0)$. For Δ_b between 0.1 and 0.01 and for $\epsilon_d < -\Delta_b$, we find this estimate to be within ~10% of the full self-consistent value.

Figure 2 presents the LDOS [Eq. (2)] versus ω , for the simple SIAM, with the parameters as indicated. Our approximation reproduces the Kondo peak at low *T*, in addition to the much broader peak at ϵ_d . Figure 3 shows ρ_d at the Fermi energy (ω =0) versus ϵ_d . Note the very slow (logarithmic) increase of $\rho_{d\sigma}$ with decreasing *T*, in agreement with Eq. (61).





FIG. 2. (Color online) The LDOS on the dot, for the simple SIAM, with $\epsilon_d = -0.3$, $\Delta_b = 0.1$, and T = 0,0.01,0.05 (all energies are in units of *J*). The Kondo peak values near $\omega = 0$, shown with more detail in the lower panel, decrease with increasing *T*.

We now turn to the conductance G. For the simple SIAM, one has^{13,14}

$$\widetilde{\mathcal{G}}(\omega) = -\frac{4\Gamma_{\ell}\Gamma_{r}}{\Gamma_{\ell} + \Gamma_{r}} \operatorname{Im} G_{dd}(\omega).$$
(66)

Equation (53) implies that

Im
$$G_{dd} = -(1 - C)\Delta_b |G_{dd}|^2$$
. (67)

For T=0, when $\mathcal{C} \to 0$, we also have $\tilde{\mathcal{G}}(\omega) = 4\Gamma_{\ell}\Gamma_{r}|G_{dd}|^{2}$. At finite temperatures, these two expressions for the conductance exhibit the same qualitative behavior as ρ_{d} (Fig. 3). The quantitative difference between the two expressions, which increases with *T* and with large negative ϵ_{d} , represents a breakdown of unitarity which may be an artifact of our approximation.



FIG. 3. The LDOS at the Fermi energy, $\rho_d(0)$, versus ϵ_d , for $T=0, 10^{-30}, 10^{-10}, 10^{-3}$ and $\Delta_b=0.1$; $\rho_d(0)$ increases with decreasing *T*.



FIG. 4. "Transmission" and "transmission phase" (in units of π) for the simple SIAM, for $\Delta_b = 0.1$ and for T = 0, 10^{-10} , 10^{-3} .

At low T, $(-\partial f/\partial \omega)$ is practically a δ function, and Eq. (3) yields $\mathcal{G} \approx (2e^2/h)\tilde{\mathcal{G}}(0)$, exhibiting the qualitative behavior shown in Fig. 3. At higher T, the peak in \mathcal{G} slightly below $\epsilon_d=0$ becomes lower and broader than that of $\rho_d(\omega=0)$. At fixed $\epsilon_d < 0$, increasing T results with a decreasing \mathcal{G} , but with an interesting superimposed peak at $T=O(|\epsilon_d|)$ (when the peak at ϵ_d starts to contribute).

Some experiments⁴ place the QD on one branch of an open Aharonov-Bohm interferometer, and attempt to extract the transmission phase for scattering through the dot. The transmission phase is usually related to the phase of G_{dd} .²⁰ Without getting into the question of what is really measured in the interferometer,³² it is still of interest to study the latter phase. Figure 4 thus shows the "transmission," represented by $\Delta_b^2 |G_{dd}|^2$, and the "transmission phase," represented by [see Eq. (65)] $\alpha = \pi(1 - \tilde{n}/2)$ as a function of ϵ_d for several temperatures. Interestingly, at high T this phase simply grows smoothly from zero to π through the resonance, similarly to the noninteracting case or to the Coulomb blockade case. However, as T decreases, the peak in the "transmission" broadens toward negative ϵ_d , eventually reaching a plateau for T=0 (see also Fig. 3). At the same time, the phase develops an intermediate plateau at $\pi/2$.²⁰ This plateau begins at an energy ϵ_d which is roughly given by $T \sim T_K(\epsilon_d)$, as defined in Eq. (60). Studying the energy where this phase grows from zero to $\pi/2$ thus suggests another way to define the crossover temperature T_K .

VI. EXAMPLE 2: THE QD ON A "T" NETWORK

Our equations also become very simple for the "T" network, when the dot sits on a side branch. Such a network has recently attracted both theoretical^{24,25} and experimental²³ interest, as the simplest realization of the Fano-Kondo effect. The mesoscopic network now consists of a single site "0." This site has one bond connected to the dot, with hopping J_x , and two bonds connected to two leads, with hopping J_ℓ and J_r . In this case, the matrix F_{11} in Appendix A is of order



FIG. 5. Conductance of the "T" network, with $J_x=0.2$, $\Delta_b=0.1$ (all in units of *J*). Thin lines, without interactions. Thick lines, with infinite interactions at T=0 (intermediate thickness lines, $T=10^{-5}$). Upper panel, $\epsilon_0=0$. Lower panel, $\epsilon_0=-.1$.

 1×1 , and Eqs. (A3) and (A8) yield $\mathcal{F}_{00} = 1/[\omega - \epsilon_0 + e^{i|q|a}(|J_\ell|^2 + |J_r|^2)/J]$. Using Δ_b from Eq. (63), we have

$$\Sigma_0(\omega) = \frac{|J_x|^2}{\omega - \epsilon_0 + e^{i|q|a}\Delta_b} \equiv \delta \epsilon_d(\omega) - i\Delta(\omega).$$
(68)

In this case, $\tilde{\mathcal{G}}$ of Eq. (3) is given by²⁵

$$\widetilde{\mathcal{G}}(\omega) = -\frac{4\Gamma_{\ell}\Gamma_{r}}{\Gamma_{\ell} + \Gamma_{r}} \operatorname{Im} G_{00}(\omega).$$
(69)

The calculation of G_{00} follows directly from Eqs. (24) and (25),

$$G_{00} = \frac{1 + \Sigma_0 G_{dd}}{\omega - \epsilon_0 + e^{i|q|a} \Delta_b}.$$
(70)

Therefore, Im G_{00} is a linear combination of Re G_{dd} and Im G_{dd} , with coefficients that depend only on the noninteracting parameters.

These equations reproduce those found, e.g., in Refs. 24 and 25. However, at this point those authors use complicated numerical schemes to obtain G_{dd} , which do not allow for systematic studies of the dependence on the various parameters. In contrast, we can easily obtain the approximate G_{dd} analytically, with the same ease as for the previous example. All we need to do is to substitute Eq. (68) into Eqs. (49)–(52).

For the noninteracting case, G_{dd} is simply given by Eq. (5). Figure 5 then compares the results for the conductance (in units of $2e^2/h$), with and without interactions. Without interactions (thin lines), for $\epsilon_0=0$ the upper panel in Fig. 5 shows a symmetric Fano vanishing of the conductance at

 $\epsilon_d=0$. As ϵ_0 becomes more negative (lower panel there), the conductance assumes a typical nonsymmetric Fano shape, with smaller conductances at large $|\epsilon_d|$. The interactions (thick lines) have a negligible effect at $\epsilon_d \ge 0$, when the dot is not occupied. However, at $\epsilon_d < 0$ and T=0 (thickest lines) the interactions cause strong changes. For $\epsilon_0=0$ and large negative ϵ_d , the occupation on the dot causes the so-called anti-Kondo effect,²⁴ where the formation of the Kondo singlet causes destructive interference which yields zero conductance. For $\epsilon_0 < 0$, the Fano zero is shifted to lower ϵ_d , the peak disappears, and the asymptotic conductance decreases. As *T* increases (medium thick lines), the behavior at negative ϵ_d gradually returns to that of the noninteracting case, and the Fano zero disappears: the conductance is always nonzero. Again, all of these phenomena are qualitatively similar to those found in Refs. 23–25.

A slightly more complex "T" network is obtained by placing another noninteracting site, "1," between the site 0 and the dot, with energy ϵ_1 and with hopping elements J_x to both site 0 and the dot. Our mesoscopic system now contains two sites, 0 and 1, and the methods of Appendix A yield

$$\Sigma_0 = \frac{J_x^2(\omega - \epsilon_0 + e^{i|q|a}\Delta_b)}{D},\tag{71}$$

$$G_{00} = \frac{\omega - \epsilon_1}{D} + \frac{J_x^4}{D^2} G_{dd}, \qquad (72)$$

with

$$D = (\omega - \epsilon_1)(\omega - \epsilon_0 + e^{i|q|a}\Delta_b) - J_x^2.$$
(73)

Figure 6 shows a few examples on how the interplay between ϵ_0 and ϵ_1 can change the dependence of the conductance on ϵ_d for the fully interacting case at T=0. For ϵ_1 $=\epsilon_0=0$, the graph looks exactly like that for the simple SIAM, discussed in Sec. V. Clearly, the presence of the intermediate point turned the destructive interference into a constructive one. Changing ϵ_0 to positive (negative) values then simply shifts the whole curve to the left (right). Changing ϵ_1 to nonzero values generates either a "Fano" zero in the conductance (when $\epsilon_0 < 0$), similar to the results in Fig. 5, or a "Fano" resonance (when $\epsilon_0 > 0$). At $\epsilon_0 = 0$ one observes a change from a zero to a resonance as ϵ_1 changes from positive to negative values. All of these parameters can be easily changed using the various gate voltages, e.g., in the setup of Ref. 23. Without going into much further discussion, it is clear that the intermediate point on the side branch is very effective in changing the interference pattern between Fano-Kondo resonances and antiresonances. Data from such experiments can then be used to obtain information on G_{dd} .

VII. DISCUSSION

We have derived an approximate analytic expression for a complex mesoscopic network, which contains a quantum dot with electron-electron interactions, and which may connect to several leads. Our formulas correct and generalize earlier expressions, and give a good qualitative interpolation between the Fermi-liquid behavior at very low temperatures and the simpler high-temperature one.



FIG. 6. Conductance of the "T" network, with an extra site "1" between the dot and the "intersection" site "0." Plots are for $U=\infty$, T=0, $J_x=0.2$, $\Delta_b=0.1$ (all in units of J). From top to bottom, ϵ_0 = 0.3, 0, -0.3. For each value of ϵ_0 , the figure contains graphs for $\epsilon_1=-0.5$, 0, 0.5, with increasing thickness.

Although our formulas reproduce many features required by the Fermi-liquid theory, they are still approximate, and should thus only be used for discussing the qualitative variation of various quantities with the parameters characterizing the network. However, the simplicity of our expressions allows for relatively easy comparisons with experiments and with more complicated numerical work.

We have demonstrated the use of our formulas for the two simple cases of a single quantum dot attached to two leads and of the "T" network, where the dot is connected to another site which couples to the two leads. Indeed, we have reproduced and extended all the expected phenomena for these two cases. In an upcoming publication³⁰ we shall apply this scheme to the interesting case of the Aharonov-Bohm interferometer.

VIII. ACKNOWLEDGMENTS

We acknowledge helpful discussions with A. Schiller, and support to Y.M. from the Israel Science Foundation (ISF). This project was carried out in a center of excellence supported by the ISF (O.E. and A.A.).

APPENDIX A: CALCULATING $\mathcal{F} = \mathcal{M}^{-1}$

We need to invert the matrix $\mathcal{M} = \omega + i \eta - \mathcal{H}_{net}$. We start by dividing our Hilbert space into two parts, called "1" and "2." Then, we write

$$\mathcal{M} = \begin{pmatrix} M_{11} & M_{12} \\ M_{21} & M_{22} \end{pmatrix},$$
(A1)

and the inverse matrix \mathcal{F} as

$$\mathcal{F} = \begin{pmatrix} F_{11} & F_{12} \\ F_{21} & F_{22} \end{pmatrix}.$$
 (A2)

It is now easy to obtain the Dyson-like equation

$$F_{11} = (M_{11} - M_{12}[M_{22}]^{-1}M_{21})^{-1}.$$
 (A3)

In our calculations we only need \mathcal{F}_{mn} for m, n within the finite mesoscopic part of the network (possibly including the dot). Identifying this part with the subspace "1" above, we thus only need the matrix elements of the finite matrix F_{11} . To obtain these via Eq. (A3), we need the Green function for the leads, $[M_{22}]^{-1}$. For our Eq. (12), the matrix M_{22} separates for the different leads, and we end up with

$$F_{22} = \left[M_{22} - \sum_{L} \Sigma^{(L)} \right]^{-1}, \tag{A4}$$

with the self-energy matrices

$$\Sigma_{mn}^{(L)} = -\sum_{rs} J_{mr} g_{rs}^{(L)} J_{sm}.$$
 (A5)

Here, the matrices M_{22} and $\Sigma^{(L)}$ are all of order $N \times N$, where N is the number of sites in the mesoscopic part of the network. Also,

$$g_{rs}^{(L)} = \sum_{k} \frac{\langle r|k\rangle\langle k|s\rangle}{\omega - \epsilon_{k}} \tag{A6}$$

is the Green function for the disconnected lead L.

For the one-dimensional leads, we use the identity

$$\frac{2}{\Omega} \sum_{k} \frac{1}{\omega + i\eta - \epsilon_{k}} = \frac{1}{2iJ \sin|q|a},$$
 (A7)

with $\omega = -2J \cos qa$, to obtain the self-energy due to the lead *L*, which is attached at the single point n_L ,

$$\Sigma^{(L)}(\omega)_{mn} = -|J_{\ell}|^2 e^{i|q|a} \delta_{m,n_L} \delta_{n,n_L}/J.$$
(A8)

The same result also applies when the mesoscopic part is empty, and the leads are connected directly to the dot.

APPENDIX B: DETAILS OF THE EOM FOR $\Gamma^{(2)}$

Following the same logic that led to Eqs. (22) and (33), the formal solution to Eq. (34) gives

$$-\sum_{n} J_{dn} \Gamma_{n\sigma}^{(2)} = \Sigma_0 \Gamma_{\sigma} - \sum_{mn} J_{dm} \mathcal{F}_{mn} [\langle X_n \rangle G_{dd\sigma} + \langle d_{-\sigma}^{\dagger} a_{n-\sigma} \rangle \\ \times (1 + \Sigma_0 G_{dd\sigma})]. \tag{B1}$$

Calculating the thermal average $\langle d^{\dagger}_{-\sigma}a_{n-\sigma}\rangle$ via the fluctuation-dissipation Eq. (32), and using Eqs. (20) and (24), we end up with an integral which requires the sum

$$S_1 = \sum_{mn\ell} J_{dm} \mathcal{F}(\omega)_{m\ell} \mathcal{F}(\omega')_{\ell n} J_{nd}.$$
 (B2)

For this and for similar sums, it is helpful to use the identity

$$\mathcal{F}(\omega + i\eta)\mathcal{F}(\omega' \pm i\eta') = \frac{\mathcal{F}(\omega' \pm i\eta') - \mathcal{F}(\omega + i\eta)}{\omega - \omega' + i\eta},$$
(B3)

which follows from Eq. (26), together with a careful use of $1/(x+i\eta) = \mathcal{P}(1/x) - i\pi\delta(x)$. Using Eq. (23), the sum in Eq. (B2) then becomes

$$S_1 = \frac{1}{\omega - \omega' + i\eta} [\Sigma_0(\omega') - \Sigma_0(\omega)].$$
(B4)

Similar manipulations allow the calculation of the thermal averages $\langle X_n \rangle$. Finally, we end up with

$$-\sum_{n} J_{dn} \Gamma_{n\sigma}^{(2)} = \Sigma_{0} \Gamma_{\sigma} + G_{dd\sigma} \int \left(-\frac{d\omega'}{2\pi i} \right) \frac{f(\omega')}{\omega - \omega' + i\eta} \\ \times \left[(1 + \Sigma_{0}' G'_{dd-\sigma}) (\Sigma_{0} - \Sigma_{0}') - (\omega' \to {\omega'}^{*}) \right] \\ - (1 + \Sigma_{0} G_{dd\sigma}) \int \left(-\frac{d\omega'}{2\pi i} \right) \frac{f(\omega')}{\omega - \omega' + i\eta} \\ \times \left[G'_{dd-\sigma} (\Sigma_{0} - \Sigma_{0}') - (\omega' \to {\omega'}^{*}) \right].$$
(B5)

As explained after Eq. (36), $G_{dd\sigma}$ and Σ_0 are understood to be functions of $\omega \rightarrow \omega + i\eta$, and the primes denote a dependence on $\omega' \rightarrow \omega' + i\eta$, with ${\omega'}^* \rightarrow \omega' - i\eta$.

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